

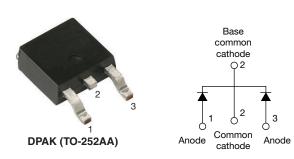
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Vishay Semiconductors

COMPLIANT HALOGEN

FREE

Hyperfast Rectifier, 2 x 4 A FRED Pt®



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 4 A					
V_{R}	200 V					
V _F at I _F	0.95 V					
t _{rr} (typ.)	23 ns					
T _J max.	175 °C					
Package	DPAK (TO-252AA)					
Circuit configuration	Common cathode					

FEATURES

- · Hyperfast recovery time
- 175 °C max. operating junction temperature
- · Output rectification freewheeling
- Low forward voltage drop reduced Q_{rr} and soft recovery
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V_{RRM}		200	V			
Average rectified forward current	I _{F(AV)}	T _C = 164 °C	8	۸			
Non-repetitive peak surge current per leg	I _{FSM}	T _J = 25 °C	80	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-			
		I _F = 4 A	-	0.87	0.95	.,		
Forward voltage per leg	V _F	I _F = 8 A -		0.95	1.10	V		
Forward voltage per leg		I _F = 4 A, T _J = 150 °C	=.	0.71	0.80			
		I _F = 8 A, T _J = 150 °C	=.	0.8	1.0			
	I _R	$V_R = V_R$ rated -		-	4			
Reverse leakage current per leg		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	=.	-	40	μΑ		
		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	=.	-	80			
Junction capacitance per leg	C _T	V _R = 200 V	-	17	-	pF		
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	8	-	nH		





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A$, $dI_F/dt = 1$	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		23	27	
Reverse recovery time	t _{rr}	T _J = 25 °C	$I_F = 4 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_B = 160 \text{ V}$	1	20	-	ns
		T _J = 125 °C			27	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	2	-	А
		T _J = 125 °C		1	3.4	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C] "		20	-	~C
		T _J = 125 °C	1	-	46	-	nC

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance,	per leg	D		-	2.7	3.2	°C/W	
junction to case	per device	R_{thJC}		-	1.35	1.6	C/VV	
A					0.3		g	
Approximate weight					0.01		OZ.	
Marking device			Case style DPAK (TO-252AA)	8CWH02FNH				



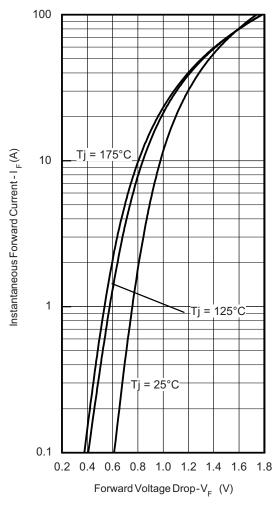


Fig. 1 - Typical Forward Voltage Drop Characteristics

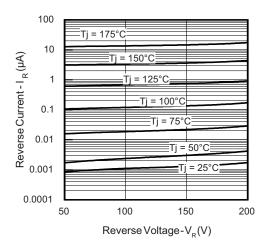


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

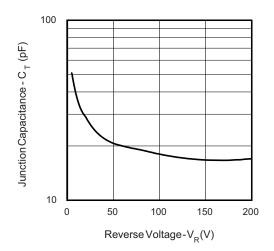


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

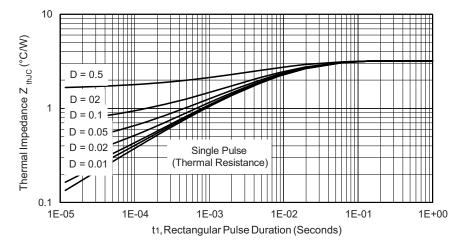


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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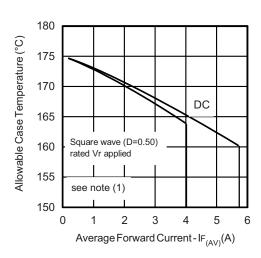


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

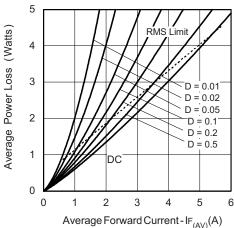
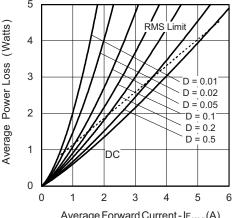
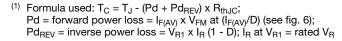


Fig. 6 - Forward Power Loss Characteristics



Note



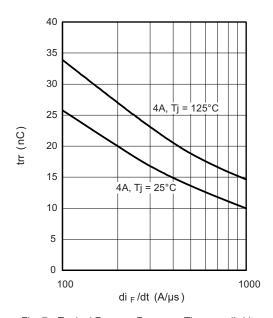


Fig. 7 - Typical Reverse Recovery Time vs. dl_E/dt

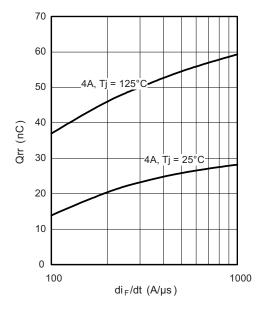


Fig. 8 - Typical Stored Charge vs. dl_F/dt

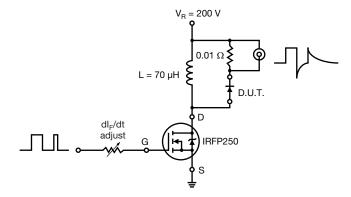
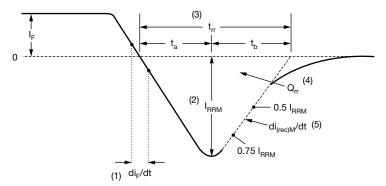


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_F$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

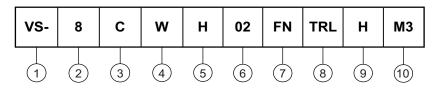
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Circuit configuration:

C = Common cathode

Package identifier:

W = D-PAK

5 - H = Hyperfast recovery

6 - Voltage rating (02 = 200 V)

7 - FN = TO-252AA

8 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

9 - H = AEC-Q101 qualified

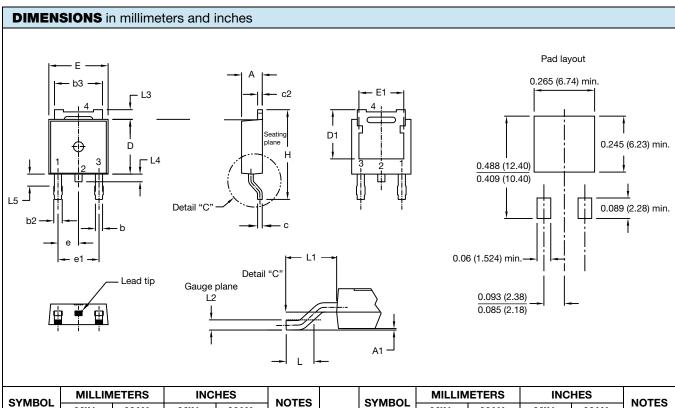
10 - Environmental digit:

M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-8CWH02FNHM3	75	3000	Antistatic plastic tube				
VS-8CWH02FNTRHM3	2000	2000	13" diameter reel				
VS-8CWH02FNTRRHM3	3000	3000	13" diameter reel				
VS-8CWH02FNTRLHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95519			
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			

DPAK (TO-252AA)



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	0.090 BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	0.51 BSC		BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
					•

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (5) Outline conforms to JEDEC® outline TO-252AA



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